NSN 5962-00-434-3046

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View Online at https://aerobasegroup.com/nsn/5962-00-434-3046

view Offilite at https://defobasegroup.com/his//0302-00-404-3040
Body Outside Diameter:
Between 0.335 inches and 0.370 inches
Body Height:
Between 0.165 inches and 0.180 inches
Maximum Power Dissipation Rating:
500.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Monolithic and hermetically sealed and high gain and negative outputs and positive outputs and low power
Inclosure Material:
Glass and metal
Inclosure Configuration:
Can
Input Circuit Pattern:
2 input
Case Outline Source And Designator:
T0-99 joint electron device engineering council
Terminal Surface Treatment:
Gold
Voltage Rating And Type Per Characteristic:
22.0 volts power source
Time Rating Per Chacteristic:
300.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Rom
Precious Material And Location:
Terminal surface gold
Precious Material:
Gold
Test Data Document:
30221-44a340319 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
8 pin
Shelf Life:
N/a
Unit Of Measure:

Yes - demil/mli

Demilitarization:

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